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# Intermarriage of InVO<sub>4</sub> and BiVO<sub>4</sub> via cation-exchange to boost charge separation for efficient photocatalytic CH<sub>4</sub> oxidation to oxygenates

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Achieving efficient and highly selective conversion of CH<sub>4</sub> into high-value-added chemicals through photodriving under mild conditions remains a significant challenge, primarily due to the limited utilization efficiency of photogenerated carriers. Herein, we report an in-situ growth strategy for constructing a robust InVO<sub>4</sub>-based heterojunction by intermarrying InVO<sub>4</sub> and BiVO<sub>4</sub> through cation-exchange. This method enables the resultant InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction to possess strong interfacial electronic coupling, which accelerates the interface charge transfer and significantly enhances the separation efficiency of photogenerated carriers. Under visible light-driven reaction conditions at ambient temperature and pressure, the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction demonstrates high selectivity (>90%) in photocatalyzing the oxidation of CH<sub>4</sub> to high-value oxygenated hydrocarbons (CH<sub>3</sub>OH and HCHO), with a yield of 318.9 µmol g<sup>-1</sup> h<sup>-1</sup>, which is 4.8 times higher than that of pristine BiVO<sub>4</sub>. Comprehensive control and isotope tracing experiments, as well as in-situ detection of transient species reveal that the key intermediate product CH<sub>3</sub>OOH is primarily formed through the binding of ·CH<sub>3</sub> radicals with protons and O<sub>2</sub>, explaining why the oxygen source of the CH<sub>3</sub>OH product is mainly derived from O<sub>2</sub>.

cation-exchange, CH<sub>4</sub> conversion, charge separation, photocatalysis, vanadate

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#### Introduction

Natural gas has emerged as a prominent economic resource of the 21st century, distinguished by its continually expanding proven reserves and increasing extraction rates. However, methane (CH<sub>4</sub>), the primary component of natural gas, exhibits a greenhouse effect significantly more potent than CO<sub>2</sub> [1,2]. If CH<sub>4</sub> can be efficiently converted into highvalue products under mild conditions, it would not only enhance its utilization value but also alleviate the substantial

costs and potential climate and environmental issues associated with natural gas transportation [3,4]. Nevertheless, the

chemical inertia of the C-H bonds poses a significant chal-

lenge for achieving direct conversion of CH<sub>4</sub> under mild conditions [5-8]. Currently, the high-efficiency catalysts

used for the direct conversion of CH4 are mostly rare and

expensive noble metals such as platinum and palladium, and

the reaction conditions often require high-energy inputs like

CH<sub>4</sub> to high-value-added products under mild conditions

high temperatures and high pressures. This is far from achieving the desired scalability and economy for CH<sub>4</sub> conversion in industry [9–14]. The replacement of traditional thermal catalysis with photocatalysis for the oxidation of

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signifies a highly promising and emerging green technology [15–18].

In recent years, a diverse array of photocatalysts (such as TiO2, ZnO, BiVO4, and CeO2) have been developed to achieve photocatalytic oxidation of CH4 into high-valueadded products [19-28]. Nonetheless, these photocatalysts often suffer from low photocatalytic efficiency [29–31], due to the contradiction between the thermodynamic driving force required for the reaction and their light-harvesting capabilities, as well as the issue of severe carrier recombination. Additionally, the oxidation products derived from CH<sub>4</sub> are more prone to further oxidation than CH<sub>4</sub> itself, leading to excessive oxidation and compromised selectivity of the desired products. Among the numerous semiconductor photocatalysts developed, BiVO<sub>4</sub> is widely used in photocatalytic CH<sub>4</sub> oxidation due to its excellent visible light absorption and photo-oxidation capabilities [32]. However, pure BiVO<sub>4</sub> is hampered by severe photogenerated carrier recombination and limited reduction ability stemming from its overly positive reduction potential, leading to low photocatalytic activity for CH<sub>4</sub> oxidation [33]. Combining BiVO<sub>4</sub> with other semiconductors that possess a strong reducing ability to construct a Z-scheme heterojunction can enhance its reducing ability while improving the efficiency of photogenerated carrier separation [34,35]. Nevertheless, the interfaces of heterojunctions fabricated through traditional techniques, such as electrostatic self-assembly and insitu deposition, lack the necessary tightness, resulting in inefficient charge transfer at the interface.

To overcome this obstacle, we herein present an in-situ cation-exchange strategy for the construction of a BiVO<sub>4</sub>based direct Z-scheme heterojunction, by introducing Bi<sup>34</sup> ions onto an InVO<sub>4</sub> substrate to form BiVO<sub>4</sub> (Figure 1a). The resultant InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction can not only preserve the excellent oxidation performance of BiVO<sub>4</sub> and the superior reduction ability of InVO<sub>4</sub>, but also possess a strong interfacial electronic coupling due to the tightly bonded interface, significantly promoting the migration and separation of photogenerated carriers. As anticipated, the prepared InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction can achieve efficient photocatalytic conversion of CH<sub>4</sub> into high value-added oxygenated hydrocarbons under room temperature, atmospheric pressure, and visible light irradiation, utilizing atmospheric oxygen as an oxidant. The yield of oxygenated hydrocarbon products for InVO<sub>4</sub>/BiVO<sub>4</sub> reaches up to 318.9 μmol g<sup>-1</sup> h<sup>-1</sup> with a selectivity of 94.5%, far superior to that of BiVO<sub>4</sub> alone. Moreover, the photogenerated carrier separation pathways within InVO<sub>4</sub>/BiVO<sub>4</sub>, as well as the reaction mechanism of photocatalytic CH<sub>4</sub> oxidation, have been comprehensively elucidated by incorporating photophysical characterization, isotope-tracing experiments, and in-situ detection of transient species.

#### 2 Results and discussion

## 2.1 Structural and morphological characterization

The crystal structures of the InVO<sub>4</sub>/BiVO<sub>4</sub> composite, pris-

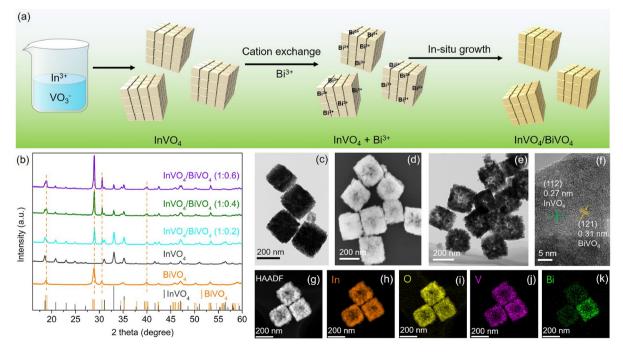


Figure 1 (Color online) (a) Schematic illustration of the preparation processes of InVO<sub>4</sub>/BiVO<sub>4</sub>. (b) XRD patterns of various photocatalysts. (c) TEM image of InVO<sub>4</sub>. SEM (d), TEM (e), HRTEM (f), and HAADF-STEM (g) images of InVO<sub>4</sub>/BiVO<sub>4</sub>. (h–k) EDS mapping images (In, O, V, Bi) of InVO<sub>4</sub>/BiVO<sub>4</sub>.

tine InVO<sub>4</sub> and BiVO<sub>4</sub> were analyzed by X-ray diffraction (XRD) measurements. As depicted in Figure 1b, the characteristic diffraction peaks of the prepared InVO<sub>4</sub> substrate can be well matched with the orthorhombic phase of InVO<sub>4</sub> (JCPDS No. 48-0898), and the XRD pattern of pristine BiVO<sub>4</sub> reveals a monoclinic phase (JCPDS No. 14-0688). For the as-prepared InVO<sub>4</sub>/BiVO<sub>4</sub> composite, apart from the distinct diffraction peaks of InVO<sub>4</sub>, the diffraction peaks at 28.8°, 30.5°, and 40.2°, contributed by BiVO<sub>4</sub> can also be clearly identified. Their intensities are gradually enhanced with the increase in the introduced Bi<sup>3+</sup> cation content, indicating the successful construction of the InVO<sub>4</sub>/BiVO<sub>4</sub> composite through *in-situ* growth of BiVO<sub>4</sub> via cation-exchange, without altering the crystal structure of the InVO<sub>4</sub> substrate.

The transmission electron microscopy (TEM) and scanning electron microscopy (SEM) measurements revealed that the pristine InVO<sub>4</sub> exhibits a regular cubic morphology (200–300 nm) composed of small cubic nanoparticles (20–30 nm) (Figure 1c, Figure S1, Supporting Information online). The InVO<sub>4</sub>/BiVO<sub>4</sub> composite, obtained by in-situ growth of BiVO<sub>4</sub> on InVO<sub>4</sub> substrate via cation-exchange strategy, still maintains the cubic structure with unchanged dimensions compared to pristine InVO<sub>4</sub> (Figure 1d, e). This indicates that the morphological characteristics of InVO<sub>4</sub> were preserved during the conversion process. High-resolution TEM (HRTEM) image of InVO<sub>4</sub>/BiVO<sub>4</sub> shows that the prepared InVO<sub>4</sub> belongs to the orthorhombic phase, with a lattice spacing of 2.7 Å clearly observed for the (112) crystalline plane of InVO<sub>4</sub>. Additionally, a lattice spacing of 3.1 Å, corresponding to the (121) crystalline plane of monoclinic phase BiVO<sub>4</sub>, is also discernible in the HRTEM image of InVO<sub>4</sub>/BiVO<sub>4</sub> (Figure 1f). Moreover, energy-dispersive X-ray spectroscopy (EDS) mapping measurements demonstrated that In, V and O elements are uniformly distributed on the InVO<sub>4</sub> substrate (Figure S2), while Bi elements are uniformly distributed throughout the InVO<sub>4</sub>/ BiVO<sub>4</sub> composite (Figure 1g-k, Figure S3), indicating that BiVO<sub>4</sub> in the InVO<sub>4</sub>/BiVO<sub>4</sub> composite is evenly dispersed on the surface of the InVO<sub>4</sub> substrate. These results further confirmed the successful transformation and uniform loading of BiVO<sub>4</sub> on the InVO<sub>4</sub> substrate. The surface areas of the samples were obtained from the isothermal N<sub>2</sub> adsorptiondesorption curves of InVO<sub>4</sub>/BiVO<sub>4</sub>, InVO<sub>4</sub> and BiVO<sub>4</sub>. The results revealed that the surface area of the InVO<sub>4</sub> substrate exceeded that of BiVO<sub>4</sub>, and the surface area of InVO<sub>4</sub>/ BiVO<sub>4</sub> was close to that of InVO<sub>4</sub> (Figure S4). This indicated that the structural characteristics of the InVO<sub>4</sub> substrate remained unchanged during the conversion process, which was consistent with the results of the TEM measurements. Additionally, the larger surface area was favorable for the catalyst to fully contact the reaction substrate, thereby enhancing catalytic activity.

High resolution X-ray photoelectron spectroscopy (XPS) measurements were further employed to investigate the interaction between InVO<sub>4</sub> and BiVO<sub>4</sub> in the as-prepared InVO<sub>4</sub>/BiVO<sub>4</sub> composites. As depicted in the XPS survey spectrum of InVO<sub>4</sub>/BiVO<sub>4</sub> (Figure S5), In, Bi, V, and O elements can be clearly identified. Notably, the binding energies of In 3d of the InVO<sub>4</sub>/BiVO<sub>4</sub> sample exhibit a significant positive shift (~0.25 eV) compared to pure InVO<sub>4</sub>, while the characteristic peaks of Bi 4f shift towards the lower binding energy by 0.30 eV compared to pristine BiVO<sub>4</sub> (Figure S6). Additionally, the binding energies of V 2p in the InVO<sub>4</sub>/BiVO<sub>4</sub> composite fall between the corresponding binding energies of V 2p in pristine InVO<sub>4</sub> and BiVO<sub>4</sub> (Figure S7). These apparent changes in the binding energy imply a strong electronic coupling between InVO<sub>4</sub> and BiVO<sub>4</sub> in the InVO<sub>4</sub>/BiVO<sub>4</sub> composite, indicating a closely contacted interface between InVO4 and BiVO4 via cationexchange in-situ growth, which will facilitate interfacial charge transfer at the InVO<sub>4</sub>/BiVO<sub>4</sub> interface. The direction of binding energy shifts of these elements indicates the occurrence of free electron transfer from InVO4 to BiVO4 during the *in-situ* growth of BiVO<sub>4</sub> on the InVO<sub>4</sub> substrate, ultimately leading to the formation of a built-in electric field directed from InVO<sub>4</sub> to BiVO<sub>4</sub>.

#### 2.2 Charge transport mechanism

To elucidate the underlying physical mechanisms responsible for the generation of the built-in electric field and the migration pathway of photogenerated carriers at the InVO<sub>4</sub>/BiVO<sub>4</sub> interface, the energy band structures of InVO<sub>4</sub> and BiVO<sub>4</sub> were first evaluated by ultraviolet-visible diffuse reflectance spectrum (UV-vis DRS) measurements. As illustrated in Figure S8, both InVO<sub>4</sub> and BiVO<sub>4</sub> demonstrate a robust responsiveness within the visible light range. By analyzing the corresponding Tauc plots, the band gaps  $(E_G)$ of InVO<sub>4</sub> and BiVO<sub>4</sub> can be determined to be 2.08 and 2.15 eV (Figure S9), respectively, which align with previous reports on these materials [36,37]. Furthermore, the valence band (VB) edge potentials ( $E_{VB}$ ) of InVO<sub>4</sub> and BiVO<sub>4</sub> were established to be 1.53 and 2.26 V (vs. SHE pH = 7), respectively, based on ultraviolet photoelectron spectroscopy (UPS) measurements (Figure 2a). Consequently, the conduction band (CB) edge potentials ( $E_{CB}$ ) of InVO<sub>4</sub> and  $BiVO_4$  can be calculated from the difference between  $E_G$  and  $E_{\rm VB}$ , being -0.55 and 0.11 V vs. SHE, respectively, which are in close proximity to the flat-band potentials of InVO<sub>4</sub> and BiVO<sub>4</sub> derived from their Mott-Schottky plots (Figure S10). The resultant staggered energy structures between InVO<sub>4</sub> and BiVO<sub>4</sub> are illustrated in Figure 2b.

The Fermi levels of  $InVO_4$  and  $BiVO_4$  were further determined by UPS measurements, being -4.19 and -5.25 eV, respectively. When  $BiVO_4$  grows *in-situ* on  $InVO_4$  through

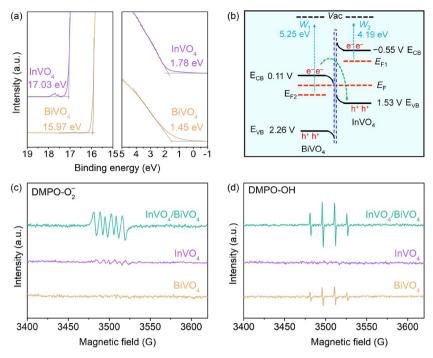


Figure 2 (Color online) (a) The UPS spectra of InVO<sub>4</sub> and BiVO<sub>4</sub>. (b) Energy band structures of InVO<sub>4</sub> and BiVO<sub>4</sub>, and the schematic illustration of the charge-transfer mechanism of the direct Z-scheme in InVO<sub>4</sub>/BiVO<sub>4</sub>. EPR spectra of (c) DMPO-O<sub>2</sub><sup>-</sup> and (d) DMPO-OH for InVO<sub>4</sub>, BiVO<sub>4</sub>, and InVO<sub>4</sub>/BiVO<sub>4</sub>.

cation-exchange, the higher Fermi level of InVO<sub>4</sub> relative to BiVO<sub>4</sub> will drive the migration of free electrons from InVO<sub>4</sub> to BiVO<sub>4</sub>, ultimately unifying the Fermi level of the entire system. This deduction is consistent with the results of the XPS analysis presented above. Additionally, the transfer of free electrons from InVO4 to BiVO4 will cause the energy bands of InVO<sub>4</sub> and BiVO<sub>4</sub> to bend upward and downward, respectively, as illustrated in Figure 2b. It is evident that the band bending of InVO<sub>4</sub> and BiVO<sub>4</sub>, coupled with the built-in electric field formed between them, will impede the separation of photogenerated carriers in the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction via the traditional dual-channel charge transfer pathway. Instead, they encourage the recombination of photogenerated electrons in BiVO<sub>4</sub> with photogenerated holes in InVO<sub>4</sub>, facilitating photogenerated carrier separation according to a Z-scheme transfer mechanism as visualized in Figure 2b. To verify this inference, *in-situ* irradiated X-ray photoelectron spectroscopy (ISI-XPS) measurements were employed to investigate the photogenerated carrier transfer orientation at the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction interface [38,39]. The results show that the binding energies of In 3d in the InVO<sub>4</sub>/BiVO<sub>4</sub> shift negatively before and after light irradiation, while the binding energies of Bi 4f shift towards higher binding energy (Figure S11). These photoexcitationinduced changes in elemental binding energies indicate the transfer of photogenerated electrons from BiVO<sub>4</sub> to InVO<sub>4</sub> in the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction, confirming a Z-scheme charge transfer mechanism for photogenerated carriers in the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction.

To further validate the Z-scheme transfer route of photogenerated carriers in InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction, the redox capacities of InVO4, BiVO4 and InVO4/BiVO4 were examined by radical trapping experiments with 5,5-dimethyl-1pyrroline-N-oxide (DMPO) as the radical trapping agent [40]. As illustrated in Figure 2c, BiVO<sub>4</sub> exhibits no detectable DMPO-O2 signals after irradiation, due to the insufficient driving force of photogenerated electrons in the conduction band of BiVO<sub>4</sub> ( $E_{CB} = 0.11 \text{ V vs. SHE}$ ) to reduce  $O_2$  to  $O_2^-$  (-0.33 V vs. SHE). Compared with InVO<sub>4</sub> alone, the significantly enhanced DMPO-O<sub>2</sub> characteristic peaks were detected in the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction. This observation suggests that the photoelectrons in the conduction band of InVO<sub>4</sub> in the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction are greatly retained and not transferred to the conduction band of BiVO<sub>4</sub>. Meanwhile, significant DMPO-OH signals were detected for BiVO<sub>4</sub>; however, no characteristic signals of DMPO-OH were observed for InVO<sub>4</sub> as presented in Figure 2d, because the valence band of InVO<sub>4</sub> ( $E_{VB} = 1.53 \text{ V } vs.$ SHE) has a more negative oxidation potential relative to the oxidation of H<sub>2</sub>O to OH radicals. However, stronger DMPO-OH signals can be observed for the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction, implying that the photogenerated holes in the BiVO<sub>4</sub> valence band are well preserved rather than transferred to the valence band of InVO<sub>4</sub>. These results further demonstrate the Z-scheme charge transfer mechanism in the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction. Therefore, the photogenerated electrons in the conduction band of InVO<sub>4</sub> and the photogenerated holes in the valence band of BiVO4 remained,

which endow the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction with strong redox capacities.

# 2.3 Photocatalytic methane oxidation performance

The photocatalytic activities of various catalysts towards CH<sub>4</sub> oxidation were evaluated in a specifically designed circulating flow system operated at room temperature and atmospheric pressure, using atmospheric oxygen as the oxidant (Figure S12). It is worth noting that the flow system allows a better separation of the oxidation products to prevent their excessive oxidation [13]. As depicted in Figure 3a, no significant oxidation products are observed using InVO<sub>4</sub> as the photocatalyst, which is attributed to the insufficient oxidative capacity of the photogenerated holes in InVO<sub>4</sub>. The pristine BiVO<sub>4</sub> exhibits poor photocatalytic CH<sub>4</sub> oxidation activity, with the yield of oxidation products (CH3OH, HCHO) being only 66.2 µmol g<sup>-1</sup> h<sup>-1</sup>, and the selectivity being 87.7%. Notably, the photocatalytic CH<sub>4</sub> oxidation activity of InVO<sub>4</sub>/BiVO<sub>4</sub> composites prepared through a cation-exchange strategy is significantly enhanced. The optimal photocatalytic yield for CH<sub>4</sub> oxidation to oxygenated hydrocarbons reaches 318.9 µmol g<sup>-1</sup> h<sup>-1</sup> with a selectivity of 94.5%, which is 4.8 times higher than that of BiVO<sub>4</sub> alone. Compared with other reported catalysts under similar mild conditions, the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction prepared in this work exhibits good performance in the photocatalytic oxidation of methane to oxygenates (Table S1, Supporting Information online). Additionally, the InVO<sub>4</sub>:BiVO<sub>4</sub> catalyst was further prepared by the traditional electrostatic self-assembly method for comparison (see details in the Experimental section). The measurement results reveal that the photocatalytic CH<sub>4</sub> oxidation activity of the InVO<sub>4</sub>:BiVO<sub>4</sub> catalyst is not significantly improved compared to pristine BiVO<sub>4</sub>. These findings suggest that the *in-situ* cation-exchange strategy provides the InVO<sub>4</sub>/BiVO<sub>4</sub> Z-scheme heterojunction with a more closely contacted interface, thus ensuring effective charge separation efficiency and excellent redox capability, both of which are crucial for improving the photocatalytic efficiency.

The stability of the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction catalyst was further investigated by continuous irradiation reaction in the circulating flow reactor system. As shown in Figure 3b, the catalyst can maintain excellent catalytic activity over 30 h, yielding oxygenated hydrocarbons at a rate of 8230 umol g<sup>-1</sup> with a selectivity exceeding 90%. Moreover, the yields of photocatalytic reaction products exhibit only a slight decrease after 7 repeated experiments (Figure S13), which confirms the stability of the catalyst. Further comparison of the XRD spectra before and after the reaction shows that the characteristic diffraction peaks of the components remain basically unchanged (Figure S14), suggesting that the crystal structure of the catalyst is not affected during the reaction process. In addition, the SEM measurement results show that the morphology and size of InVO<sub>4</sub>/ BiVO<sub>4</sub> after the photocatalytic reaction have hardly changed

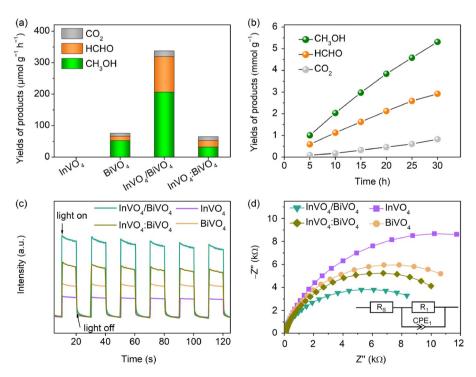


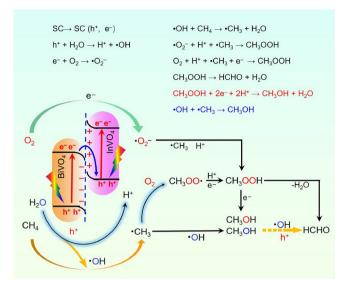
Figure 3 (Color online) (a) Yields of products with different photocatalysts in the circulating flow system, reaction conditions: 10 mg photocatalyst, the mixture of CH<sub>4</sub> and air (gas ratio of CH<sub>4</sub>/air: 10/1) at a flow rate of 20 mL min<sup>-1</sup>, 3 h of 300 W Xe lamp ( $\lambda \ge 400$  nm) irradiation at room temperature with a light intensity of 200 mW cm<sup>-2</sup>. (b) Time-on-line amounts of products by InVO<sub>4</sub>/BiVO<sub>4</sub>. *I-t* curves (c) and EIS Nyquist plots (d) of different photocatalysts.

compared to those of InVO<sub>4</sub>/BiVO<sub>4</sub> before the reaction (Figure S15). All of the above experimental evidence fully demonstrates the excellent photocatalytic stability of the InVO<sub>4</sub>/BiVO<sub>4</sub> composites prepared in this work.

In addition, the relationship between the photogenerated carrier separation efficiency and catalytic performance of InVO<sub>4</sub>/BiVO<sub>4</sub> composite was further investigated by employing transient photocurrent response (I-t) and electrochemical impedance spectroscopy (EIS) measurements. The I-t curves show that the photocurrent density of InVO<sub>4</sub>/ BiVO<sub>4</sub> composite is significantly higher than that of InVO<sub>4</sub> or BiVO<sub>4</sub> (Figure 3c), indicating that the photogenerated carriers transport efficiency of the heterojunction composite is greatly improved. The EIS measurements demonstrate that the charge transfer resistance of the composite is significantly smaller than those of the two single components (Figure 3d, Table S2), indicating that the *in-situ* conversion of BiVO<sub>4</sub> on InVO<sub>4</sub> can effectively separate the charges and lead to a reduced charge transfer resistance. These results illustrate again that the structure of the InVO<sub>4</sub>/BiVO<sub>4</sub> Z-scheme heterojunction composite not only enhances its oxidation and reduction capabilities, but also improves the photogenerated carrier transport efficiency, which is the microscopic origin of the enhanced photocatalytic performance. It is noteworthy that InVO<sub>4</sub>/BiVO<sub>4</sub> also exhibits a bigger photocurrent density and smaller charge transfer resistance than InVO<sub>4</sub>:BiVO<sub>4</sub>, and this is consistent with its enhanced photocatalytic activity, suggesting that InVO<sub>4</sub>/ BiVO<sub>4</sub> has a higher separation and transport efficiency of photogenerated carriers owing to the close contact interface, which is the key factor contributing to the enhancement of the photocatalytic activity.

#### 2.4 Mechanism of photocatalytic methane oxidation

Herein, a feasible mechanism of the photocatalytic CH<sub>4</sub> oxidation based on the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction is proposed in Figure 4. Specifically, the photogenerated carriers in the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction are transported following a Z-scheme mechanism, where the photogenerated holes in the valence band of InVO<sub>4</sub> are annihilated by the photogenerated electrons in the conduction band of BiVO<sub>4</sub>. The photogenerated holes in the BiVO<sub>4</sub> valence band oxidize H<sub>2</sub>O to generate OH radicals, which are key reactive species for activating the C-H bonds of CH<sub>4</sub> to generate ·CH<sub>3</sub> radicals. The obtained ·CH<sub>3</sub> radicals then can form CH<sub>3</sub>OOH through combining with protons and O<sub>2</sub> (or the ·O<sub>2</sub> radicals generated from photoelectron reduction of  $O_2$ ). Due to the inherent instability, the CH<sub>3</sub>OOH will undergo intramolecular photolytic dehydration to form HCHO or be further reduced to CH<sub>3</sub>OH by photogenerated electrons. Another source of CH<sub>3</sub>OH is the direct coupling of the produced ·CH<sub>3</sub> and ·OH radicals. Furthermore, the oxidation product CH<sub>3</sub>OH can be



**Figure 4** (Color online) Schematic diagram of the proposed reaction pathway for CH<sub>4</sub> conversion with InVO<sub>4</sub>/BiVO<sub>4</sub> as the photocatalyst.

further oxidized to HCHO by OH radicals or photogenerated holes, representing an alternative pathway for HCHO production.

The origin of ·OH radicals can be confirmed through a series of control experiments conducted using fluorescent probe molecules (coumarin) [41]. As demonstrated in Figure S16, the generation of OH radicals is undetectable in the absence of either BiVO<sub>4</sub> or H<sub>2</sub>O. In contrast, when both BiVO<sub>4</sub> and H<sub>2</sub>O are present, a bright fluorescent signal resulting from the combination of the fluorescent probe molecules with ·OH radicals is clearly observable. Furthermore, the disappearance of the OH radical signal is apparent when triethylamine (Et<sub>3</sub>N) is used as the photogenerated hole annihilator in the BiVO<sub>4</sub> and H<sub>2</sub>O reaction system. Based on the above experimental results, it can be preliminarily determined that the ·OH radicals originate from the oxidation of H<sub>2</sub>O by the photogenerated holes of BiVO<sub>4</sub>. Additionally, it is clearly evident that the fluorescence signal is significantly enhanced when the air in the reaction system is replaced by pure O<sub>2</sub>, indicating that the presence of O<sub>2</sub> has a prominent promotion effect on the generation of OH radicals (Figure S17). Notably, the fluorescence signal of OH radicals is further enhanced by using Ag<sup>+</sup> ions as the electron annihilator instead of O2. It can be inferred that the enhanced fluorescence signal in the O<sub>2</sub> atmosphere is not a result of the reduction of O2 to OH radicals, but rather due to the presence of O<sub>2</sub> consuming the photogenerated electrons and promoting the photogenerated carrier separation, which in turn leads to a higher efficiency of photogenerated holes in oxidizing H<sub>2</sub>O to produce ·OH radicals. The origin of the ·OH radicals was further determined by isotope labeling experiments. It is distinctly apparent that only 7-18OH-coumarin (m/z = 164) is observed when  $^{16}O_2$  and  $H_2^{18}O$  as

feedstocks (Figure 5a), demonstrating that the  $\cdot$ OH radicals do indeed originate from the oxidation of  $H_2O$  rather than from the photoreduction of  $O_2$ .

The mechanism of C-H bond oxidation was investigated by radical trapping experiments using DMPO as a radical trapping agent. As illustrated in Figure 5b, when H<sub>2</sub>O is the only absent component in the detection system, no radical signal can be detected, indicating that the photogenerated holes are insufficient to activate C-H bonds. When H<sub>2</sub>O is present but CH<sub>4</sub> is absent, the DMPO-OH signal becomes clearly visible. It is noteworthy that when the system contains both H<sub>2</sub>O and CH<sub>4</sub>, the signals of DMPO-OH and DMPO-CH<sub>3</sub> can be detected simultaneously [42]. In addition, the signals of ·CH<sub>3</sub> radicals are gradually enhanced with increasing irradiation time, while the signals of ·OH radicals are weakened, which is mainly attributed to the fact that the ·OH radicals consume their own quantity while oxidizing CH<sub>4</sub> to produce ·CH<sub>3</sub> radicals. Furthermore, the radical signal intensities of the InVO<sub>4</sub>/BiVO<sub>4</sub> catalyst system are stronger than those of BiVO<sub>4</sub> alone, which is consistent with the photocatalytic activity results, indicating that the OH radical plays a critical role in the CH<sub>4</sub> activation process. Based on the above evidence, it is suggested that the C-H bonds of CH<sub>4</sub> are activated via H-abstraction by ·OH radicals.

The origin of the oxidation product CH<sub>3</sub>OH was further explored to elucidate the process of CH<sub>3</sub>OH generation. Firstly, isotopic labeling experiments combined with mass

spectrum analysis were conducted to determine the carbon source of the oxidation product. As shown in Figure 5c, the characteristic peaks of  $^{13}CH_3OH$  (m/z = 33) can be clearly observed in the mass spectrum when <sup>13</sup>CH<sub>4</sub> is used as the raw material, whereas only  $^{12}$ CH<sub>3</sub>OH (m/z = 32) is detected when <sup>12</sup>CH<sub>4</sub> is used as the feedstock. Moreover, distinct splitting peaks ( $\delta = 3.12$  and 3.40 ppm) belonging to <sup>13</sup>CH<sub>3</sub>OH can be observed in the proton nuclear magnetic resonance (1H NMR) spectrum of the <sup>13</sup>CH<sub>4</sub> system (Figure S18) [43]. These results confirm that the carbon source of the oxidation product CH<sub>3</sub>OH is derived from CH<sub>4</sub>. Thereafter, the reaction paths of O<sub>2</sub> and H<sub>2</sub>O were verified by examining the source of oxygen in the oxidation products. It can be clearly observed that  $CH_3^{18}OH$  (m/z = 34) is the main product when <sup>18</sup>O<sub>2</sub> and H<sub>2</sub><sup>16</sup>O are used as feedstocks, whereas the main product is  $CH_3^{16}OH$  (m/z = 32) accompanied by a small amount of CH<sub>3</sub><sup>18</sup>OH (m/z = 34) when <sup>16</sup>O<sub>2</sub> and H<sub>2</sub><sup>18</sup>O are used (Figure S19). This indicates that the source of oxygen for the oxidation product CH<sub>3</sub>OH is primarily derived from O<sub>2</sub> and partially from H<sub>2</sub>O. Furthermore, the response mechanism of O<sub>2</sub> molecules was examined by employing EPR measurements. In the system with H<sub>2</sub>O and CH<sub>4</sub>, only significant OH and CH<sub>3</sub> radical signals are detected. Upon introducing O2 into the system, it is observed that the CH3 OO radical signals are generated (Figure 5d) [44]. Therefore, it can be inferred that O<sub>2</sub> reacts with the ·CH<sub>3</sub> radicals to form the CH<sub>3</sub>OO· radicals, and these CH<sub>3</sub>OO· radicals then combine with protons aided by electrons to form the

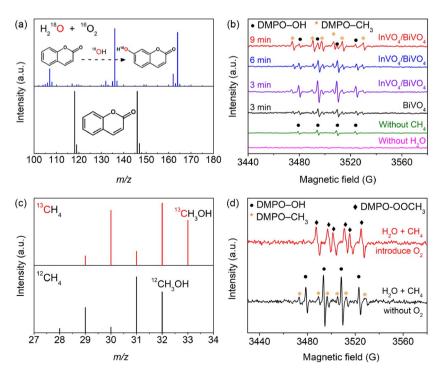


Figure 5 (Color online) (a) Mass spectra of 7-OH-coumarin generated over InVO<sub>4</sub>/BiVO<sub>4</sub> with <sup>16</sup>O<sub>2</sub> + H<sub>2</sub><sup>18</sup>O as feedstocks. (b) Comparison of EPR intensities of DMPO–OH and DMPO–CH<sub>3</sub> for various photocatalysts at different reaction times. (c) Mass spectra of CH<sub>3</sub>OH generated over InVO<sub>4</sub>/BiVO<sub>4</sub> from <sup>13</sup>CH<sub>4</sub> (top) and <sup>12</sup>CH<sub>4</sub> oxidation (below). (d) EPR spectra of DMPO–OH, DMPO–CH<sub>3</sub>, and DMPO–OOCH<sub>3</sub> before and after the introduction of O<sub>2</sub> in the photocatalytic oxidation of CH<sub>4</sub>.

CH<sub>3</sub>OOH intermediate. The presence of CH<sub>3</sub>OOH can be confirmed by <sup>13</sup>C NMR spectrum (Figure S20). No significant CH<sub>3</sub>OOH product can be detected in this reaction system because it is very easily reduced to CH<sub>3</sub>OH by photogenerated electrons [45].

The above inferences were fully validated by further control experiments with the annihilating active species (Figure S21). First, almost no oxidation product was detected in the reaction system without H<sub>2</sub>O participation. When Et<sub>3</sub>N and isopropanol (IPA) were utilized to annihilate the photogenerated holes and OH radicals, respectively, there was a substantial reduction in the amount of the oxidation products in the reaction system, implying that the OH radicals generated through the oxidation of H<sub>2</sub>O by photogenerated holes are the key active species for driving the CH<sub>4</sub> oxidation reaction. Additionally, the production of oxidation products was almost completely inhibited when the 'CH<sub>3</sub> radicals were annihilated using TEMPO, suggesting that 'CH<sub>3</sub> is an important intermediate during the generation of oxidation products. When the 'O2 radicals were annihilated by the benzoquinone (PBQ), the generation of the oxidation products was slightly inhibited, implying a non-negligible role of  $O_2^-$  in the product formation. After annihilating the photogenerated electrons using Ag<sup>+</sup> ions in the absence of O<sub>2</sub>, a small amount of oxidation product was still produced, inferring that a direct coupling reaction occurs between ·CH<sub>3</sub> and OH radicals to produce CH<sub>3</sub>OH, which is consistent with the mass spectrum showing that the oxygen source of the oxidation product is partly derived from H<sub>2</sub>O. In the absence of O<sub>2</sub> and Ag<sup>+</sup> during the reaction, almost no oxidation product was detectable. It suggests there is an indispensable role for O<sub>2</sub> to consume photogenerated electrons in promoting the oxidation of H<sub>2</sub>O by photogenerated holes to produce ·OH radicals to activate the C-H bonds of CH<sub>4</sub>, in addition to its participation in the generation of oxidation products.

### 3 Conclusions

In summary, a robust and environmentally friendly InVO<sub>4</sub>/BiVO<sub>4</sub> Z-scheme heterojunction was successfully constructed by decorating BiVO<sub>4</sub> onto InVO<sub>4</sub> via a simple cation-exchange strategy, combined with an *in-situ* transformation technology. Structural characterization and XPS measurements unveiled that the *in-situ* growth method endows the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction with strong interfacial electronic coupling, which significantly accelerates the interfacial charge transfer and enhances the separation efficiency of photogenerated carriers via the Z-scheme pathway, as evidenced by ISI-XPS, EPR and photoelectrochemical measurements. Consequently, the InVO<sub>4</sub>/BiVO<sub>4</sub> heterojunction exhibits superior performance in the photocatalytic

CH<sub>4</sub> conversion reaction, achieving an oxygenated hydrocarbon yield of 318.9 µmol g<sup>-1</sup> h<sup>-1</sup> and a selectivity of 94.5%, far outperforming both pristine BiVO<sub>4</sub> and InVO<sub>4</sub>: BiVO<sub>4</sub> counterpart prepared via electrostatic self-assembly. Furthermore, comprehensive control experiments, isotope labeling experiments, and EPR measurements disclosed that CH<sub>4</sub> activation occurs through hydrogen abstraction by ·OH radicals generated from the oxidation of water by photogenerated holes, and the key intermediate CH<sub>3</sub>OOH is primarily formed through the combination of ·CH<sub>3</sub> radicals with O<sub>2</sub> and protons.

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Conflict of interest The authors declare no conflict of interest.

**Supporting information** The supporting information is available online at <a href="http://chem.scichina.com">http://chem.scichina.com</a> and <a href="http://link.springer.com/journal/11426">http://link.springer.com/journal/11426</a>. The supporting materials are published as submitted, without typesetting or editing. The responsibility for scientific accuracy and content remains entirely with the authors.

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